

MiniSKiiP<sup>®</sup> 1

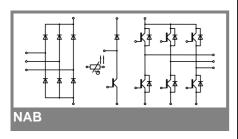
3-phase bridge rectifier + brake chopper + 3-phase bridge inverter SKIIP 10NAB12T4V1

#### **Features**

- Trench 4 IGBT's
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

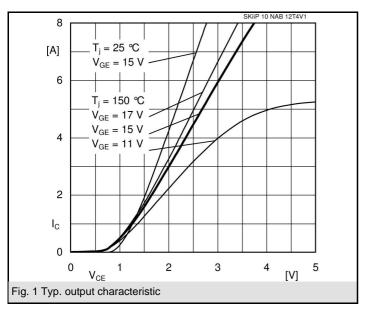
#### Remarks

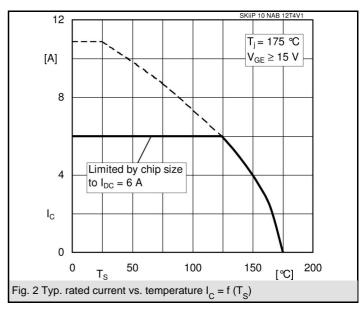
- V<sub>CEsat</sub>, V<sub>F</sub>= chip level value
- Case temp. limited to T<sub>C</sub> = 125°C max. (for baseplateless modules T<sub>C</sub> = T<sub>S</sub>)
- $T_C = T_S$ )
   product rel. results valid for  $T_j \le 150$  (recomm.  $T_{op} = -40 \dots +150$ °C)

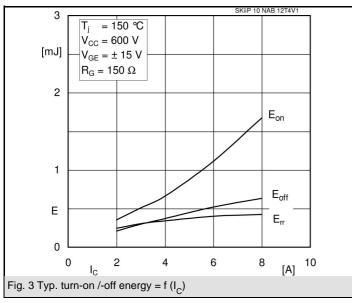


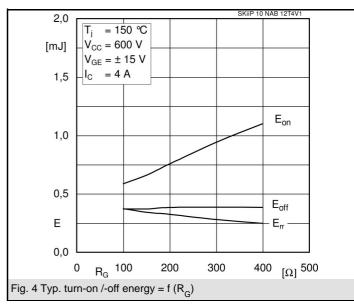
<b>Absolute Maximum Ratings</b> $T_s = 25$ °C, unless otherwise specified							
Symbol	Conditions	Values	Units				
IGBT - Inverter, Chopper							
$V_{CES}$		1200	V				
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	6 (6)	Α				
I <sub>CRM</sub>		12	Α				
$V_{GES}$		± 20	V				
T <sub>j</sub>		- 40 <b>+</b> 175	°C				
Diode - Inverter, Chopper							
I <sub>F</sub>	$T_s = 25 (70) ^{\circ}C$	15 (12)	Α				
I <sub>FRM</sub>		24	Α				
T <sub>j</sub>		- 40 <b>+</b> 175	°C				
Diode - Rectifier							
$V_{RRM}$		1600	V				
I <sub>F</sub>	T <sub>s</sub> = 70 °C	35	Α				
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms, sin 180 °, T <sub>i</sub> = 25 °C	220	Α				
i²t	$t_p^r = 10 \text{ ms, sin } 180 ^\circ, T_i^r = 25 ^\circ\text{C}$	240	A²s				
T <sub>j</sub>		- 40 <b>+</b> 150	°C				
Module							
I <sub>tRMS</sub>	per power terminal (20 A / spring)	20	Α				
T <sub>stg</sub>		- 40 <b>+</b> 125	°C				
V <sub>isol</sub>	AC, 1 min.	2500	V				

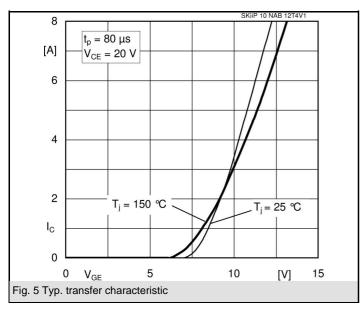
Characteristics		T <sub>s</sub> = 25 °C, unless otherwise specified							
Symbol	Conditions	min.	typ.	max.	Units				
IGBT - Inverter, Chopper									
$\begin{matrix} V_{\text{CEsat}} \\ V_{\text{GE(th)}} \\ V_{\text{CE(TO)}} \\ r_{\text{T}} \end{matrix}$	$\begin{split} &   I_{\text{Cnom}} = 4 \text{ A, T}_j = 25 \text{ (150) °C} \\ & V_{\text{GE}} = V_{\text{CE}}, I_{\text{C}} = 1 \text{ mA} \\ & T_j = 25 \text{ (150) °C} \\ & T_j = 25 \text{ (150) °C} \end{split}$	5	5,8 0,8 (0,7) 260 (390)		V V V mΩ				
C <sub>ies</sub> C <sub>oes</sub> C <sub>res</sub> R <sub>th(j-s)</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ per IGBT		0,25 0,025 0,015 2,49		nF nF nF K/W				
$\begin{array}{c} t_{d(on)} \\ t_r \\ t_{d(off)} \\ t_f \\ E_{on} \\ E_{off} \end{array}$	under following conditions $V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$ $I_{Cnom} = 4 \text{ A}, T_j = 150^{\circ}\text{C}$ $R_{Gon} = R_{Goff} = 150 \Omega$ inductive load		65 45 300 110 0,66 0,37		ns ns ns ns mJ mJ				
Diode - In	Diode - Inverter, Chopper								
$V_{F} = V_{EC}$ $V_{(TO)}$ $r_{T}$ $R_{th(j-s)}$	$I_{Fnom} = 4 \text{ A, T}_j = 25 (150) ^{\circ}\text{C}$ $T_j = 25 (150) ^{\circ}\text{C}$ $T_j = 25 (150) ^{\circ}\text{C}$ per diode		1,25 (0,85)	2,35 (2,15) 1,45 (1,05) 225 (275)	V V mΩ K/W				
I <sub>RRM</sub> Q <sub>rr</sub> E <sub>rr</sub>	under following conditions $I_{Fnom} = 4 \text{ A}, V_R = 600 \text{ V}$ $V_{GE} = 0 \text{ V}, T_j = 150 \text{ °C}$ $di_F/dt = 110 \text{ A/µs}$		3,4 0,95 0,34		Α μC mJ				
Diode - Rectifier									
$V_F$ $V_{(TO)}$ $r_T$ $R_{th(j-s)}$	$I_{Fnom} = 15 \text{ A, T}_j = 25 \text{ °C}$ $T_j = 150 \text{ °C}$ $T_j = 150 \text{ °C}$ per diode		1,1 0,8 20 1,5		V V mΩ K/W				
Temperature Sensor									
R <sub>ts</sub>	3 %, T <sub>r</sub> = 25 (100) °C		1000(1670)		Ω				
Mechanical Data									
w M <sub>s</sub>	Mounting torque	2	35	2,5	g Nm				

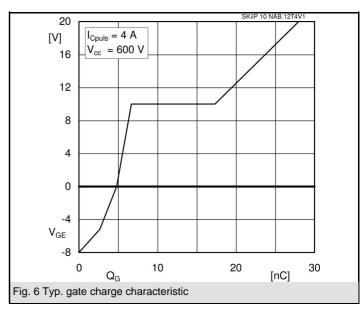


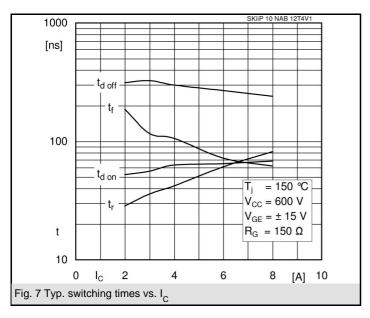


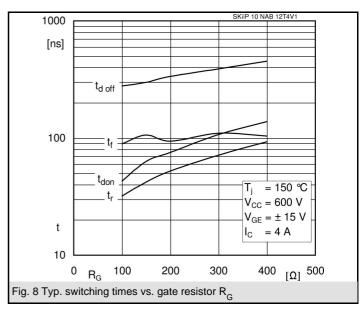


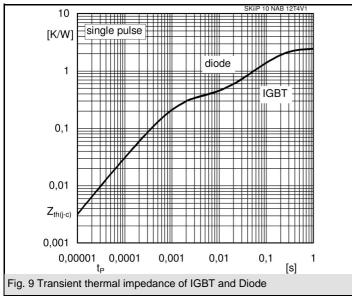


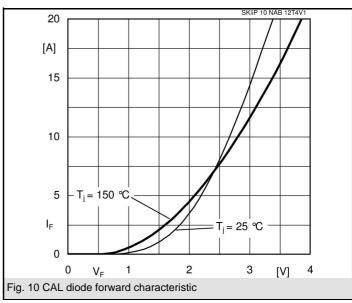


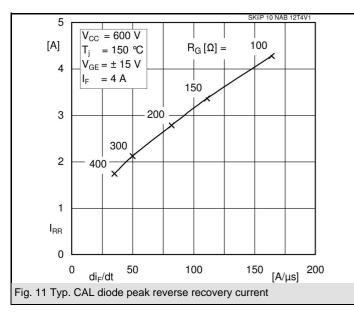


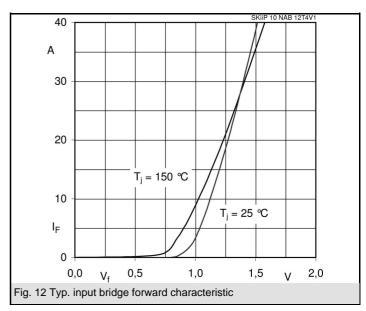


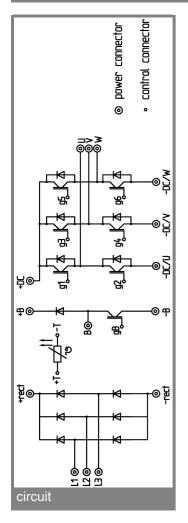


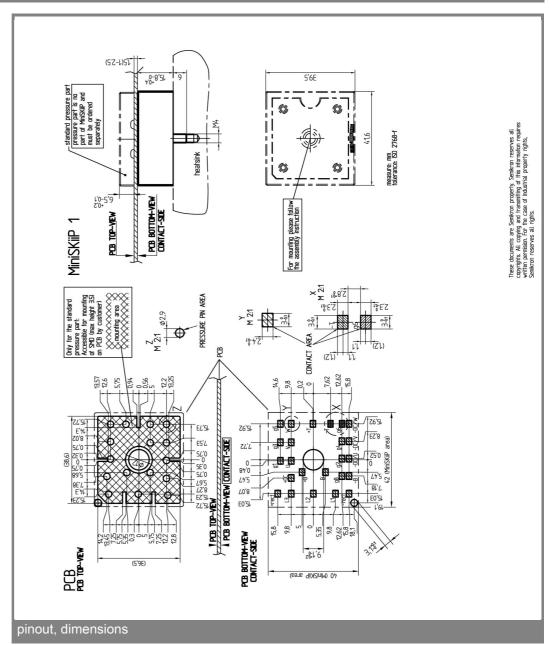












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

4 13-02-2009 LAN © by SEMIKRON

<sup>\*</sup> The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.